

**Final performance report**

**Advanced silicon photonic transceivers - the case of a wavelength  
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receiver for Terabit/s optical transmission**

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PI: Gunther Roelkens

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**Gunther Roelkens  
UNIVERSITEIT GENT VZW**

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Final Report**

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| <b>14. ABSTRACT</b><br>The PI developed silicon photonic coherent receivers that operate at 40 Gbaud and can handle advanced modulation formats by the co-integration of a passive 90 degree optical hybrid, highspeed balanced Ge photodetectors and a high-speed two-channel transimpedance amplifier. The device has record performance for an integrated silicon photonic receiver, both in terms of bitrate (160 Gbit/s per wavelength and per polarization) as well as in terms of power consumption. This makes the device very appealing for integration into larger modules, combining both wavelength and space division multiplexing to reach multiple Tb/s receiver modules.                                                                                                                                                               |                                        |                                         |                                              |                                                                             |                                                                    |
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## Summary

In this project we developed silicon photonic coherent receivers that operate at 40 Gbaud and can handle advanced modulation formats by the co-integration of a passive 90 degree optical hybrid, high-speed balanced Ge photodetectors and a high-speed two-channel transimpedance amplifier. The device has record performance for an integrated silicon photonic receiver, both in terms of bitrate (160 Gbit/s per wavelength and per polarization) as well as in terms of power consumption. This makes the device very appealing for integration into larger modules, combining both wavelength and space division multiplexing to reach multiple Tb/s receiver modules.

## Introduction

The growth of internet traffic has led to a substantial amount of research towards high-speed coherent transceivers for long-haul networks. Coherent communication offers several advantages over traditional on-off keying schemes, including compensation of linear and non-linear fiber distortions and higher spectral efficiency thanks to phase-diversity and multilevel constellations (e.g. QPSK and 16-QAM) [1]. In the near future coherent transceivers are expected to become key components in metropolitan area networks and in the long term even in access networks [2, 3]. This will require a significant reduction in size, cost, and power consumption with regards to the current implementations of coherent transceivers. The main contributor in terms of power consumption in these devices is the digital signal processor (DSP) at the receiver side. But even with the prospect of a significant power reduction for every new CMOS node, it's unlikely that the DSP will have a place inside ultra-compact pluggable modules with very stringent power budgets of only a few Watts. These modules are envisioned as fully analog coherent frontends (e.g. ACO-CFPx modules) where the signal processing is done on the motherboard. With the DSP outside the module, the coherent receiver accounts for a significant part of the power consumption and size of the transceiver. Silicon photonics emerges as an ideal platform to implement such ultra-compact and low-power integrated coherent receivers (ICRs). The circuits can be fabricated on large 200 mm or 300 mm wafers in commercial CMOS foundries allowing for high-volume and low-cost photonic integrated circuits (PICs) and the high index-contrast permits the realization of devices with very small footprint. Silicon ICRs with a symbol rate up to 30 GBaud for QPSK and 28 GBaud for 16-QAM have been demonstrated using a single polarization receiver [4, 5] and using a polarization division multiplexed (PDM) receiver [6-9]. An alternative implementation with a 120° optical hybrid using a 3x3 multimode-interferometer (MMI) instead of the traditional 90° hybrid was demonstrated in [10]. Recently, a fully monolithic single-polarization ICR where the photonic devices were realized on the same chip as the transimpedance amplifiers (TIAs) was demonstrated [11]. Here we present the project results on a single-polarization silicon coherent receiver packaged with a 2-channel SiGe TIA-array operating at 40 GBaud. The ICR achieves a bit-error ratio (BER) of  $3.8 \times 10^{-3}$  for an optical signal-to-noise ratio (OSNR) of 14 dB for 80 Gb/s QPSK modulation and 26.5 dB for 160 Gb/s 16-QAM modulation. Further, we discuss the performance of the receiver over temperature and wavelength.

## Methods, Assumptions, and Procedures

The photonic integrated circuit (PIC) is realized in imec's iSiPP25G platform and is shown in Fig 1. The circuit consists of two single-polarization grating couplers, a 2 by 4 multi-mode interferometer (2x4-MMI) acting as a 90° hybrid, and 2 pair of balanced germanium photodiodes (Ge PDs) occupying an area of 0.3 mm by 0.7 mm. The grating couplers have an efficiency of -6.5 dB and a -1 dB bandwidth of 20 nm. The MMI was designed to have a phase error of less than 5° over the C-band [4]. The simulated common mode rejection ratio, taking into account typical fabrication tolerances, is better than -20 dB. A single Ge PD has a bandwidth above 50 GHz, an on-chip responsivity of 0.5 A/W, and a dark-current of < 15 nA at -1 V bias. The photodiodes are placed in a balanced configuration, which reduces the number of bondpads and prevents a large DC-current to enter the TIA, simplifying its design. This approach does, however, double the capacitance seen by the TIA, reducing the overall bandwidth. Nonetheless, the high individual bandwidth and low capacitance per photodiode will prove sufficient for 40 GBaud operation as we will demonstrated below.

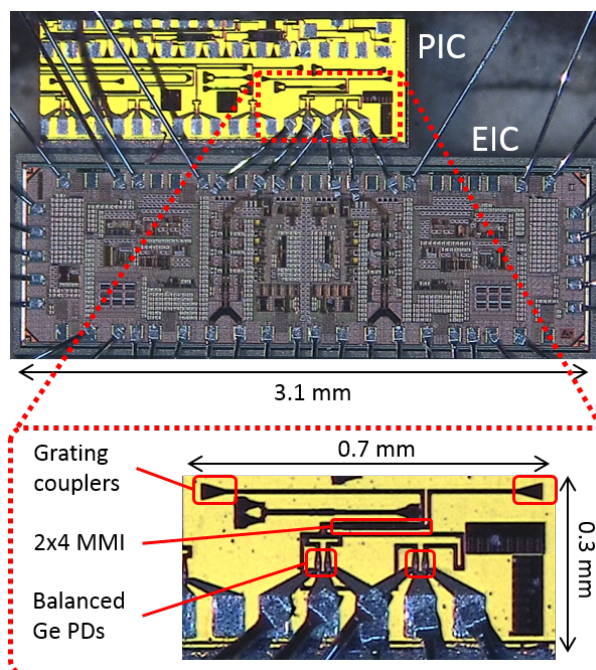


Fig. 1. Microscope photograph of the photonic integrated circuit (PIC) wirebonded to the electronic integrated circuit (EIC) together with a more detailed view of the PIC-layout. The PIC die was kept much larger than the dimensions of the coherent receiver for ease of dicing and assembly.

The electronic chip consists of a 2-channel TIA array fabricated in a 0.13  $\mu\text{m}$  SiGe BiCMOS technology. Apart from the decoupling capacitors, the TIAs also provide the biasing for the Ge PDs. The input stage of the TIA delivers a fixed voltage of 0.9 V across the bottom photodiode and a variable bias control output is set to 1.8 V, matching the voltage of the top photodiode to 0.9 V. This scheme has the benefit that it requires no negative supply voltage as in classic balanced configurations [5,7]. Moreover, all electrical connections with the PIC are provided by the electronic IC.

Besides speed and power consumption, the TIAs were optimized for linearity to be able to handle multilevel constellations (e.g. 16-QAM) [13].

Both silicon coherent receiver and TIA-array were wirebonded and placed in a cavity of a high-speed printed circuit board (PCB) to minimize the length of the EIC-to-PCB wirebonds. The PCB was not optimized in size to enable easy testing and fabrication. The  $2 \times 2$  differential outputs of the TIAs were routed symmetrically to 4 high-speed connectors. Due to the limitations of the measurement setup, all experiments were performed single-ended with one of each of the differential outputs DC-blocked and terminated with a 50  $\Omega$  resistor. This halves the maximal signal swing for a TIA-output from 400 mV to 200 mV peak-to-peak.

Fig. 2 shows the homodyne setup that was used to characterize the silicon coherent receiver, where

light from a 1550.12 nm laser (linewidth 100 kHz) serves as signal (TX) and local oscillator (LO). The signal part is fed to a IQ-Mach-Zehnder modulator (IQ-MZM) driven by two high speed DACs, and is modulated by a  $2^{15}$ -1 long pseudo random bit sequence (PRBS). Thanks to two 80 GSa/s high-speed DACs provided by MICRAM, we were able to significantly reduce the transmitter-based limitations from our previous experiments [4] and realize high quality transmission up to 40 GBaud. Amplified spontaneous emission (ASE) noise is added to the modulated light in a noise loading stage during OSNR measurements. A variable optical attenuator (VOA) provides signal power control for the receiver. The LO is amplified by a second EDFA to a desired power level. TE polarized light for both LO and TX is coupled through fiber-to-chip grating couplers to the silicon photonic IC with the aid of polarization controllers. A 50 GHz 160 GS/s real-time oscilloscope stores the output of the TIA for offline processing. The system BER was averaged over 1 and 2 million bits, for QPSK and 16-QAM respectively.

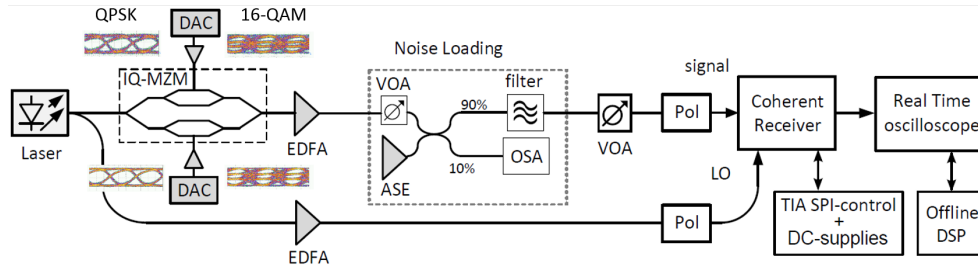


Fig. 2. Schematic of the characterization setup of the QPSK/16-QAM coherent receiver

## Results and Discussion

The bandwidth of the system (i.e. PCB, silicon coherent receiver and TIA) was measured with a Lightwave Component Analyzer (LCA) and is shown in Fig. 3. The transimpedance ( $R_F$ ) of the TIA was swept over the range of possible values, i.e.  $R_F = 400 \Omega/N$  with  $N = 1, 2, \dots, 8$ . As expected, the 3-dB bandwidth decreases inversely with  $R_F$ . For the lowest  $R_F$  values the designed gain peaking becomes visible, extending the bandwidth even further. At lowest gain (i.e. lowest  $R_F$ ) we reach a bandwidth of  $\sim 30$  GHz in good agreement with what was simulated in [4]. As the germanium photodiodes have a very high bandwidth and a slow roll-off [4], we believe that the TIAs form the bandwidth bottleneck of the ICR. During the 28 GBaud experiments  $R_F$  was set to  $133 \Omega$  (resulting in 17 GHz bandwidth) for QPSK and  $100 \Omega$  (resulting in 22 GHz bandwidth) for 16-QAM transmission. To compensate for the higher data rate in the 40 GBaud experiments the transimpedance  $R_F$  was reduced further to  $80 \Omega$  (resulting in 26 GHz bandwidth) for QPSK and  $67 \Omega$  (resulting in 28 GHz bandwidth) for 16-QAM

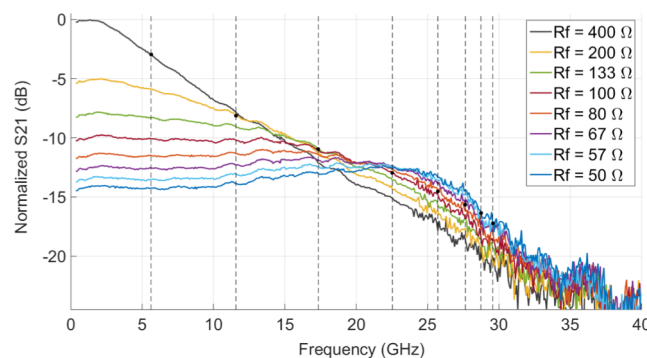


Fig. 3. Measured S21 of the coherent receiver with TIA for different transimpedances, i.e.  $R_F = 400 \Omega/N$  with  $N = 1, 2, \dots, 8$ , normalized to the low frequency gain at the largest  $R_F$  setting. The dotted vertical lines indicate the 3-dB bandwidth corresponding to the decreasing  $R_F$  values.

### A. 40 GBaud QPSK and 16-QAM Operation

For BER measurements  $-8.3$  dBm (QPSK) and  $-8.7$  dBm (16-QAM) of fiber-coupled signal power

was used, resulting in an on-chip power of -14.8 dBm and -15.2 dBm respectively). The fiber-coupled LO power was 10.7 dBm (on-chip power  $\sim 4$  dBm) for both modulations. These values were kept for all other measurements. The transimpedance of the TIA was set at  $80\ \Omega$  for QPSK and  $67\ \Omega$  for 16-QAM, as discussed above. No temperature control was used during these measurements.

Fig. 4 (a) shows the measured bit-error rate as a function of OSNR for both 28 GBaud and 40 GBaud operation. For 40 GBaud QPSK, operation below the soft-decision forward error coding (SD-FEC) threshold (BER of  $1.9 \times 10^{-2}$  for 20% overhead) is reached at an OSNR of 12.4 dB. The hard-decision FEC (HD-FEC) threshold (BER of  $3.8 \times 10^{-3}$  for 7% overhead) requires 14 dB OSNR. For 16-QAM this requires 22 dB and 26.5 dB OSNR, respectively. An example of the received constellation for QPSK (at 20 dB OSNR) can be found in Fig. 4 (b) and for 16-QAM (at 30 dB OSNR) in Fig. 4 (c).

The measured BER curve for 40 GBaud QPSK is in good approximation a  $\sim 2.5$  dB shifted version of the 28 GBaud curve. Theoretically a transition from 28 to 40 GBaud requires a 1.55 dB increase in OSNR [14], indicating that transmission at 40 Gbaud adds approximately 1 dB to the OSNR penalty with respect to the theoretical minimum. For QPSK the penalty compared to the theoretical minimum, taken at SD-FEC level, amounts to  $< 2.5$  dB for 56 Gb/s and  $< 3.5$  dB for 80 Gb/s. As 16-QAM puts additional requirements on the receiver (e.g. linearity) the deviation from the theoretical OSNR limit is more pronounced at  $\sim 4.5$  dB (112 Gb/s) and  $\sim 7$  dB (160 Gb/s), respectively.

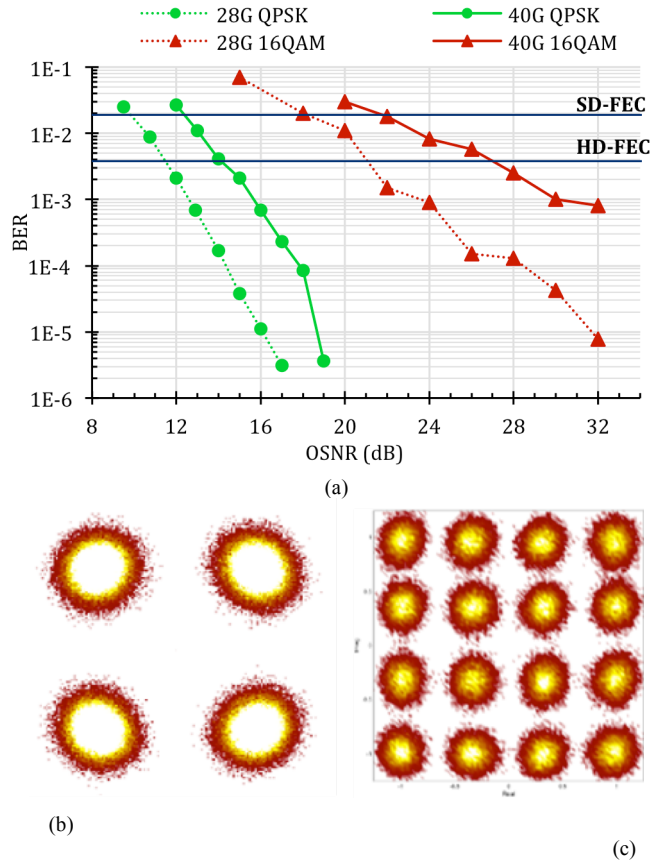


Fig. 4. (a) Measured BER versus OSNR (0.1 nm bandwidth). QPSK is shown as green and 16-QAM as red, 28 GBaud curves are dotted, 40 GBaud curves are full; Received constellations for (b) 80 Gb/s QPSK with 20 dB OSNR and (c) 160 Gb/s 16-QAM with 30 dB OSNR.

### B. Wavelength dependence

To evaluate the wavelength dependence of the coherent receiver, we sent 40 GBaud 16-QAM symbols on different carriers in the C-band. The optical filter bank that was used in the noise loading stage had a limited frequency span, preventing us of covering the complete C-band. Operation over  $\sim 25$  nm centered around 1550.12 nm ( $\lambda_c$ ) was studied as seen in Fig. 5. The OSNR was kept constant (corresponding to a BER of  $\sim 2.5 \times 10^{-3}$  at 1550.12 nm) and no temperature control was used. The

closer to the edges of the C-band the higher the resulting BER was, corresponding to a maximal OSNR penalty of  $\sim 2$  dB compared to center of the C-band. We attribute this to the limited optical bandwidth of the grating coupler having an excess insertion loss of 2.5 dB at  $\lambda_c \pm 12.5$  nm. Replacing the grating couplers by edge couplers would provide a more broadband solution covering the whole C-band [9].

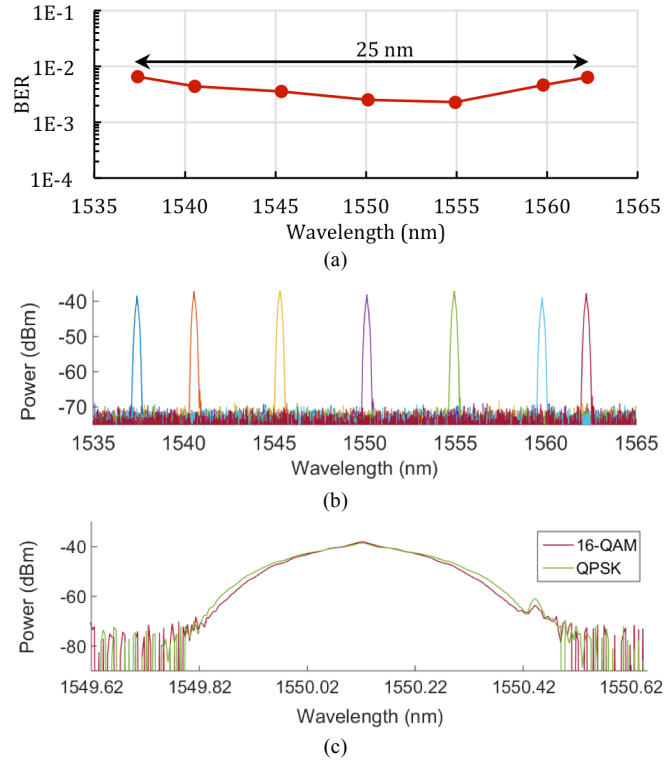


Fig. 5. (a) Wavelength dependence of the coherent receiver in the C-band in terms of BER measured over a range of  $1550 \text{ nm} \pm 12.5 \text{ nm}$  for 40 GBaud 16-QAM. (b) Optical spectra for each investigated channel. (c) Detailed example of an optical spectra for a carrier at 1550.12 nm.

## Conclusions

We demonstrated for the first time a high-performance integrated silicon coherent receiver operating at 40 GBaud QPSK (80 Gb/s) and 16-QAM (160 Gb/s). The ICR shows robust operation over almost  $60^\circ\text{C}$  with no significant OSNR penalty for QPSK. For 16-QAM there is a  $\sim 1$  dB penalty for temperatures up to  $60^\circ\text{C}$ . The limited bandwidth of the fiber-to-chip grating couplers introduces an OSNR penalty of  $\sim 2$  dB for channels near the edges of the C-band, but this could be eliminated with edge couplers. In [4], we showed that the presented receiver also featured an extremely compact PIC ( $0.3 \text{ mm} \times 0.7 \text{ mm}$ ) and low power consumption of the co-designed TIAs (310 mW) compared to the state-of-art silicon ICRs. With the addition of a polarization-beam splitter a 320 Gb/s PDM-ICR could be realized using two copies of the single-polarization receiver that consumes only 0.62 W (excluding the LO laser). Combining all these aspects, the ICR reported in this paper presents an important building block for future generation small form-factor pluggable modules (e.g. ACO-CFP4 or QSFP28), paving the way for low-power and low-cost silicon transceivers in metro and access networks at 200G and beyond.

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## List of Symbols, Abbreviations and Acronyms

|      |                                         |
|------|-----------------------------------------|
| QPSK | quadrature phase shift keying           |
| QAM  | quadrature amplitude modulation         |
| DSP  | digital signal processing               |
| ACO  | analog coherent                         |
| CFP  | C form factor pluggable                 |
| ICR  | integrated coherent receiver            |
| CMOS | complementary metal-oxide-semiconductor |
| PIC  | photonic integrated circuit             |
| PDM  | polarization division multiplexing      |
| MMI  | multimode interferometer                |
| TIA  | transimpedance amplifier                |
| DC   | direct current                          |
| PD   | photodetector                           |
| PCB  | printed circuit board                   |
| EIC  | electronic integrated circuit           |
| IQ   | in-phase/quadrature                     |
| MZM  | Mach-Zehnder modulator                  |
| DAC  | digital to analog converter             |
| OSNR | Optical signal to noise ratio           |
| VOA  | variable optical attenuator             |
| ASE  | amplified spontaneous emission          |
| LO   | local oscillator                        |
| TX   | transmitter                             |
| LCA  | lightwave component analyzer            |
| BER  | bit error rate                          |
| FEC  | forward error correction                |